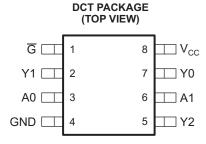


## FEATURES

- Available in the Texas Instruments NanoFree<sup>™</sup> Package
- Supports 5-V V<sub>CC</sub> Operation
- Inputs Accept Voltages to 5.5 V •
- Max t<sub>nd</sub> of 5.1 ns at 3.3 V •
- Low Power Consumption, 10-µA Max Icc •
- ±24-mA Output Drive at 3.3 V •
- Typical V<sub>OLP</sub> (Output Ground Bounce) <0.8 V at  $V_{CC} = 3.3$  V,  $T_A = 25^{\circ}C$
- Typical V<sub>OHV</sub> (Output V<sub>OH</sub> Undershoot) >2 V at  $V_{CC} = 3.3 \text{ V}, T_{A} = 25^{\circ}\text{C}$



I <sub>off</sub> Supports Partial-Power-Down Mode
Operation
Latch-IIn Performance Exceeds 100 mA

- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

I	DCU PACKAGE (TOP VIEW)				PACKA TOM V	
G [	1	8	□ V <sub>cc</sub>	GND	O 4 5 O	Y2
	2	7	□ Y0	A0	O 3 6 O	A1
	3	6	□ A1	Y1	O 2 7 O	Y0
	4	5	□ Y2	G	O 1 8 O	V <sub>CC</sub>

See mechanical drawings for dimensions.

## **DESCRIPTION/ORDERING INFORMATION**

This decoder is designed for 1.65-V to 5.5-V  $V_{CC}$  operation.

The SN74LVC1G29 is a 2-of-3 decoder/demultiplexer. When the enable  $(\overline{G})$  input signal is low, only one of the outputs is in the low state, depending on the input levels of A0 and A1. When G is high, Y0, Y1, and Y2 are high, regardless of the input states.

#### ORDERING INFORMATION

T <sub>A</sub>	PACKAGE (1	)	ORDERABLE PART NUMBER	TOP-SIDE MARKING (2)	
	NanoFree™ – WCSP (DSBGA) 0.23-mm Large Bump – YZP (Pb-free)	Reel of 3000	SN74LVC1G29YZPR	D9_	
-40°C to 85°C		Reel of 3000	SN74LVC1G29DCTR	000	
	SSOP – DCT	Reel of 250	SN74LVC1G29DCTT	C29	
	VSSOP – DCU	Reel of 3000	SN74LVC1G29DCUR	C20	
	V3SOF - DC0	Reel of 250	SN74LVC1G29DCUT	- C29_	

(1) Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

DCT: The actual top-side marking has three additional characters that designate the year, month, and assembly/test site. (2) DCU: The actual top-side marking has one additional character that designates the assembly/test site. YZP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the assembly/test site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. NanoFree is a trademark of Texas Instruments.

## SN74LVC1G29 2-OF-3 DECODER/DEMULTIPLEXER

SCES569B-JUNE 2004-REVISED JANUARY 2007

## **DESCRIPTION/ORDERING INFORMATION (CONTINUED)**

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disable the outputs, preventing damaging current backflow through the device when it is powered down.

**IEXAS** 

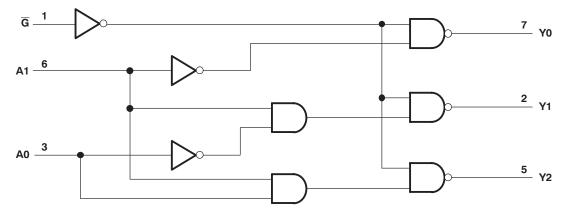
TRUMENTS www.ti.com

NanoFree<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

	INPUTS			OUTPUTS	
G	A1	A0	Y0	Y1	Y2
L	L	Х	L	Н	Н
L	Н	L	Н	L	Н
L	н	Н	н	н	L
н	х	Х	н	н	н

#### **FUNCTION TABLE**

#### LOGIC DIAGRAM (POSITIVE LOGIC)



## Absolute Maximum Ratings<sup>(1)</sup>

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{CC}$	Supply voltage range		-0.5	6.5	V
VI	Input voltage range (2)	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high-im	-0.5	6.5	V	
Vo	Voltage range applied to any output in the high or	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>0</sub> < 0		-50	mA
I <sub>O</sub>	Continuous output current			±50	mA
	Continuous current through V <sub>CC</sub> or GND			±100	mA
		DCT package		220	
$\theta_{JA}$	Package thermal impedance <sup>(4)</sup>	DCU package		227	°C/W
		YZP package		102	
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

(3) The value of  $V_{CC}$  is provided in the recommended operating conditions table.

(4) The package thermal impedance is calculated in accordance with JESD 51-7.

# Recommended Operating Conditions<sup>(1)</sup>

			MIN	MAX	UNIT	
v	Supply voltage	Operating	1.65	5.5	V	
V <sub>CC</sub>	Supply voltage	Data retention only	1.5		V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65 \times V_{CC}$			
	Lligh lovel input veltage	V <sub>CC</sub> = 2.3 V to 2.7 V	1.7		V	
V <sub>IH</sub>	High-level input voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$	2		V	
		$V_{CC} = 4.5 V \text{ to } 5.5 V$	$0.7  imes V_{CC}$			
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35\times V_{CC}$		
.,		V <sub>CC</sub> = 2.3 V to 2.7 V		0.7	V	
V <sub>IL</sub>	Low-level input voltage	$V_{CC} = 3.0 \text{ V} \text{ to } 3.6 \text{ V}$		0.8	v	
		V <sub>CC</sub> = 4.5 V to 5.5 V		$0.3  imes V_{CC}$		
VI	Input voltage		0	5.5	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 1.65 V		-4		
	DH High-level output current	V <sub>CC</sub> = 2.3 V		8		
l <sub>он</sub>		<u> </u>		-16	mA	
		$V_{CC} = 3 V$		-24		
		$V_{CC} = 4.5 V$		-32		
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		8		
OL	Low-level output current	N 2)/		16	mA	
		$V_{CC} = 3 V$		24		
		V <sub>CC</sub> = 4.5 V		32		
		$V_{CC}$ = 1.8 V ± 0.15 V, 2.5 V ± 0.2 V		20		
Δt/Δv	Input transition rise or fall rate	$V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}$		10	ns/V	
		V <sub>CC</sub> = 5 V ± 0.5 V		5		
Γ <sub>A</sub>	Operating free-air temperature		-40	85	°C	

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004. SCES569B-JUNE 2004-REVISED JANUARY 2007

### **Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	MIN	TYP <sup>(1)</sup>	MAX	UNIT
	$I_{OH} = -100 \ \mu A$	1.65 V to 5.5 V	V <sub>CC</sub> – 0.1			
V <sub>OH</sub>	$I_{OH} = -4 \text{ mA}$	1.65 V	1.2			
	$I_{OH} = -8 \text{ mA}$	2.3 V	1.9			V
	$I_{OH} = -16 \text{ mA}$	- 3 V	2.4			v
	$I_{OH} = -24 \text{ mA}$	- 3V	2.3			
	$I_{OH} = -32 \text{ mA}$	4.5 V	3.8			
	I <sub>OL</sub> = 100 μA	1.65 V to 5.5 V			0.1	
	I <sub>OL</sub> = 4 mA	1.65 V			0.45	
N/	I <sub>OL</sub> = 8 mA	2.3 V			0.3	V
V <sub>OL</sub>	I <sub>OL</sub> = 16 mA	- 3 V			0.4	v
	I <sub>OL</sub> = 24 mA	- 3V			0.55	
	I <sub>OL</sub> = 32 mA	4.5 V			0.55	
l <sub>l</sub>	V <sub>1</sub> = 5.5 V or GND	0 to 5.5 V			±1	μA
I <sub>off</sub>	$V_1 \text{ or } V_0 = 5.5 \text{ V}$	0			±10	μA
I <sub>CC</sub>	$V_{I} = 5.5 \text{ V or GND}, \qquad I_{O} = 0$	1.65 V to 5.5 V			10	μA
$\Delta I_{CC}$	One input at $V_{CC}$ – 0.6 V, Other inputs at $V_{CC}$ or GND	3 V to 5.5 V			500	μA
CI	$V_{I} = V_{CC} \text{ or } GND$	3.3 V		3.5		pF

(1) All typical values are at V<sub>CC</sub> = 3.3 V,  $T_A = 25^{\circ}C$ .



## **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = ± 0.1			: 2.5 V .2 V	V <sub>CC</sub> = ± 0.3		V <sub>CC</sub> = ± 0.5		UNIT
	(INPOT)	(001F01)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or G	Y	2.5	15.4	1.5	7.1	1	5.1	0.5	4.2	ns

### **Switching Characteristics**

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  or 50 pF (unless otherwise noted) (see Figure 2)

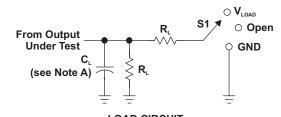
PARAMETER	FROM (INPUT)	TO (OUTPUT)		: 1.8 V 15 V	V <sub>CC</sub> = ± 0.	2.5 V 2 V	V <sub>CC</sub> = ± 0.3		= V <sub>CC</sub> ± 0.5		UNIT
	(INPOT)	(001701)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or G	Y	2.5	15.8	1.5	7.5	1	6.1	0.5	5.1	ns

### **Operating Characteristics**

 $T_A = 25^{\circ}C$ 

	PARAMETER		TEST CONDITIONS	V <sub>CC</sub> = 1.8 V TYP	V <sub>CC</sub> = 2.5 V TYP	V <sub>CC</sub> = 3.3 V TYP	V <sub>CC</sub> = 5 V TYP	UNIT
~	Power dissipation	G to Y1	f = 10 MHz	17	17	18	19	рF
C <sub>pd</sub>	capacitance	A1 to Yn		33	33	33	35	рг

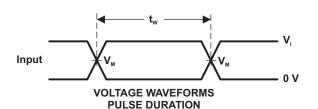
#### PARAMETER MEASUREMENT INFORMATION

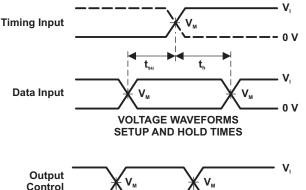


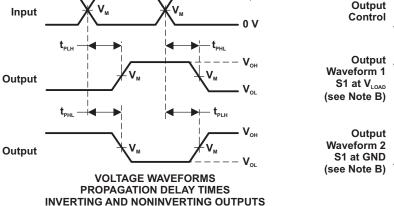
TEST	S1
t <sub>PLH</sub> /t <sub>PHL</sub>	Open
$t_{PLZ}/t_{PZL}$	VLOAD
$t_{_{PHZ}}/t_{_{PZH}}$	GND

LUAD	CIRCUIT	

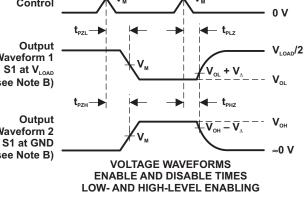
V <sub>cc</sub>	INF	PUTS	V	N	•		V	
	V	t,/t,	V <sub>M</sub>	VLOAD	CL	$R_{L}$		
1.8 V ± 0.15 V	$V_{cc}$	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	15 pF	<b>1 Μ</b> Ω	0.15 V	
$2.5 V \pm 0.2 V$	$V_{cc}$	≤2 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	15 pF	<b>1 Μ</b> Ω	0.15 V	
$3.3 V \pm 0.3 V$	3 V	≤2.5 ns	1.5 V	6 V	15 pF	<b>1 Μ</b> Ω	0.3 V	
$5 V \pm 0.5 V$	$V_{cc}$	≤2.5 ns	V <sub>cc</sub> /2	2 × V <sub>cc</sub>	15 pF	<b>1 Μ</b> Ω	0.3 V	





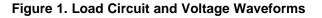


V,

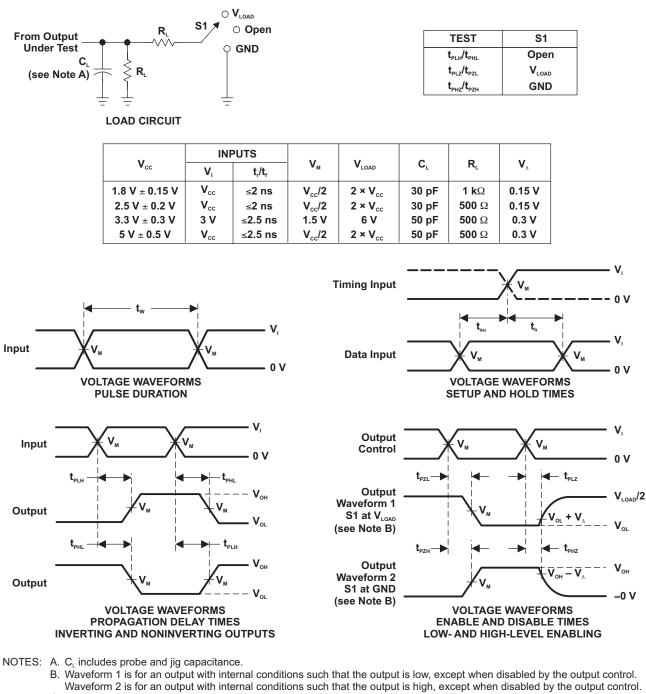


NOTES: A.  $C_{\scriptscriptstyle L}$  includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z₀ = 50 Ω.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{\text{PLZ}}$  and  $t_{\text{PHZ}}$  are the same as  $t_{\text{dis}}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.



### PARAMETER MEASUREMENT INFORMATION (continued)



- C. All input pulses are supplied by generators having the following characteristics:  $PRR \le 10 \text{ MHz}$ ,  $Z_0 = 50 \Omega$ .
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $\dot{t}_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{od}$ .
- H. All parameters and waveforms are not applicable to all devices.

#### Figure 2. Load Circuit and Voltage Waveforms



25-Jul-2013

## PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type Pack Draw	-	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVC1G29DCTR	ACTIVE	SM8 DC		8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29 Z	Samples
SN74LVC1G29DCTRE4	ACTIVE	SM8 DC	Т	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29 Z	Samples
SN74LVC1G29DCTRG4	ACTIVE	SM8 DC	т	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29 Z	Samples
SN74LVC1G29DCUR	ACTIVE	US8 DC	U	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29R	Samples
SN74LVC1G29DCURE4	ACTIVE	US8 DC	U	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29R	Samples
SN74LVC1G29DCURG4	ACTIVE	US8 DC	U	8	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29R	Samples
SN74LVC1G29DCUT	ACTIVE	US8 DC	U	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29R	Samples
SN74LVC1G29DCUTE4	ACTIVE	US8 DC	U	8	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	C29R	Samples
SN74LVC1G29YZPR	ACTIVE	DSBGA YZ	Р	8	3000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	(D97 ~ D9N)	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW**: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)



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<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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## PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVC1G29DCUR	US8	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74LVC1G29YZPR	DSBGA	YZP	8	3000	178.0	9.2	1.02	2.02	0.63	4.0	8.0	Q1

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## PACKAGE MATERIALS INFORMATION

8-Apr-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVC1G29DCUR	US8	DCU	8	3000	202.0	201.0	28.0
SN74LVC1G29YZPR	DSBGA	YZP	8	3000	220.0	220.0	35.0

## **MECHANICAL DATA**

MPDS049B - MAY 1999 - REVISED OCTOBER 2002

#### DCT (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion

D. Falls within JEDEC MO-187 variation DA.



DCT (R-PDSO-G8) PLASTIC SMALL OUTLINE Example Board Layout Example Stencil Design (Note C,E) (Note D) - 6x0,65 - 6x0,65 8x0,25-8x1,55 3,40 3,40 Non Solder Mask Defined Pad Example Pad Geometry -0,30 (Note C) 1,60 Example -0,07 Non-solder Mask Opening All Around (Note E) 4212201/A 10/11

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



DCU (R-PDSO-G8)

PLASTIC SMALL-OUTLINE PACKAGE (DIE DOWN)



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.

D. Falls within JEDEC MO-187 variation CA.



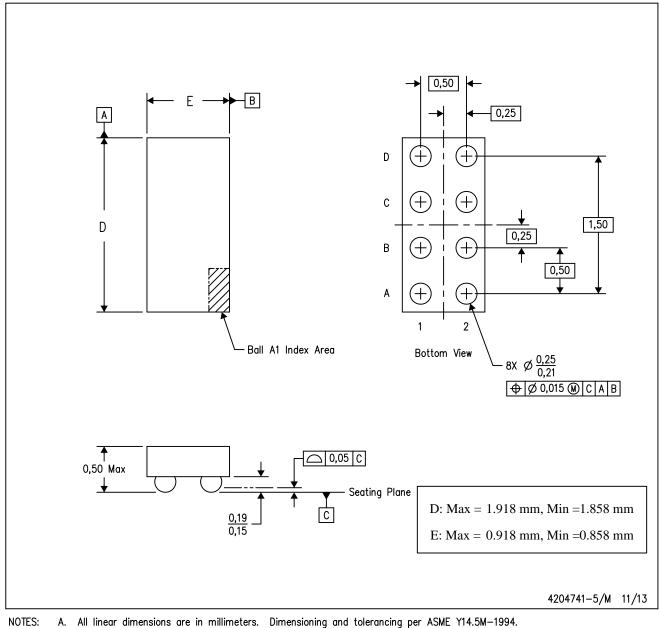


- NOTES: A. All linear dimensions are in millimeters. В. This drawing is subject to change without notice.
  - C. Publication IPC-7351 is recommended for alternate designs.
  - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
  - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



YZP (R-XBGA-N8)

DIE-SIZE BALL GRID ARRAY



- A. All linear dimensions are in millimeters. Dimension B. This drawing is subject to change without notice.
- C. NanoFree™ package configuration.

NanoFree is a trademark of Texas Instruments.



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